

# CVD Synthesis of 2D-MoS<sub>2</sub> for Heterostructure Development in Optoelectronic Devices

Tuesday, November 5, 2024 2:15 PM (15 minutes)

Molybdenum disulfide (MoS<sub>2</sub>), a two-dimensional transition metal dichalcogenide with a direct bandgap in its monolayer form, presents significant potential for a wide range of applications in optoelectronics. The heterostructure formed by combining MoS<sub>2</sub> with gallium nitride (GaN), a wide-bandgap semiconductor characterized by high electron mobility, thermal stability, and favorable optical properties, offers a platform for the development of advanced electronic device architectures.

This work details the synthesis of high-quality MoS<sub>2</sub> monolayers via Chemical Vapor Deposition (CVD) utilizing liquid precursors. The proposed method enables the formation of uniform, large-area MoS<sub>2</sub> flakes with precise control over thickness, morphology, and crystallinity, presenting a scalable approach for the integration of 2D materials. In addition, a process for transferring MoS<sub>2</sub> grown on SiO<sub>2</sub>/Si to GaN substrates is introduced and compared with the direct growth of MoS<sub>2</sub> on GaN.

Furthermore, we present preliminary exploratory results on the integration of MoS<sub>2</sub> into photonic structures, specifically bullseye cavities, to enhance light-matter interaction via the Purcell effect. This integration highlights the potential of MoS<sub>2</sub> for photonic devices, where its unique optical properties can be leveraged to achieve enhanced control over light emission.

The future outcomes of this study aim to demonstrate the versatility of CVD-grown MoS<sub>2</sub> for high-performance optoelectronic applications.

This research was supported, in part, by the PRIN Project "2DIntegrate" (Prot. 2022RHRZN2) funded by MUR under the European Union –Next Generation EU programme.

## Type of presence

Presence online

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**Session Classification:** Workshop on Sustainable Materials and Technologies

**Track Classification:** Workshop on Sustainable Materials and Technologies